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February 2008

74LVX86 Low Voltage Quad 2-Input Exclusive-OR Gate

Features

- Input voltage level translation from 5V to 3V
- Ideal for low power/low noise 3.3V applications
- Guaranteed simultaneous switching noise level and dynamic threshold performance

General Description

The LVX86 contains four 2-input exclusive-OR gates. The inputs tolerate voltages up to 7V allowing the interface of 5V systems to 3V systems.

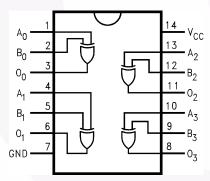
Ordering Information

| Order Number | Package Number | Package Description |
|-----------------|-------------------|--|
| 74LVX86M | M14A | 14-Lead Small Outline Integrated Circuit (SOIC), JEDEC MS-012, 0.150" Narrow |
| 74LVX86SJ | M14D | 14-Lead Small Outline Package (SOP), EIAJ TYPE II, 5.3mm Wide |
| 74LVX86MTC | MTC14 | 14-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 4.4mm Wide |

Device also available in Tape and Reel. Specify by appending suffix letter "X" to the ordering number.

All packages are lead free per JEDEC: J-STD-020B standard.

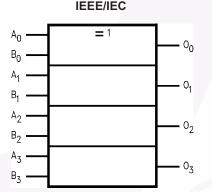
Connection Diagram

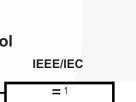


Pin Description

| Pin Names | Description |
|--------------------------------|-------------|
| A ₀ -A ₃ | Inputs |
| B ₀ –B ₃ | Inputs |
| O ₀ O ₃ | Outputs |

Logic Symbol





Absolute Maximum Ratings

Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.

| Symbol | Parameter | Rating |
|-------------------------------------|---------------------------------------|---------------------------------|
| V _{CC} | Supply Voltage | -0.5V to +7.0V |
| I _{IK} | DC Input Diode Current, $V_I = -0.5V$ | –20mA |
| VI | DC Input Voltage | –0.5V to 7V |
| I _{OK} | DC Output Diode Current | |
| | $V_{O} = -0.5V$ | –20mA |
| | $V_{\rm O} = V_{\rm CC} + 0.5 V$ | +20mA |
| Vo | DC Output Voltage | -0.5V to V _{CC} + 0.5V |
| Ι _Ο | DC Output Source or Sink Current | ±25mA |
| I _{CC} or I _{GND} | DC V _{CC} or Ground Current | ±50mA |
| T _{STG} | Storage Temperature | –65°C to +150°C |
| Р | Power Dissipation | 180mW |

Recommended Operating Conditions⁽¹⁾

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. Fairchild does not recommend exceeding them or designing to absolute maximum ratings.

| Symbol | Parameter | Rating |
|-----------------------|--------------------------|-----------------------|
| V _{CC} | Supply Voltage | 2.0V to 3.6V |
| VI | Input Voltage | 0V to 5.5V |
| V _O | Output Voltage | 0V to V _{CC} |
| T _A | Operating Temperature | –40°C to +85°C |
| $\Delta t / \Delta V$ | Input Rise and Fall Time | 0ns/V to 100ns/V |

Note:

1. Unused inputs must be held HIGH or LOW. They may not float.

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DC Electrical Characteristics

| Symbol | | | | T _A = +25°C | | | T _A = | | |
|-----------------|------------------------------|-----------------|---|------------------------|------|------|------------------|------|-------|
| | Parameter | V _{cc} | Conditions | Min. | Тур. | Max. | Min. | Max. | Units |
| V _{IH} | HIGH Level Input | 2.0 | | 1.5 | | | 1.5 | | V |
| | Voltage | 3.0 | | 2.0 | | | 2.0 | |] |
| | | 3.6 | | 2.4 | | | 2.4 | | |
| V _{IL} | LOW Level Input | 2.0 | | | | 0.5 | | 0.5 | V |
| | Voltage | 3.0 | | | | 0.8 | | 0.8 | |
| | | 3.6 | | | | 0.8 | | 0.8 | |
| V _{OH} | HIGH Level Output Voltage | 2.0 | $V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \mu A$ | 1.9 | 2.0 | | 1.9 | | V |
| | | 3.0 | $V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -50 \mu A$ | 2.9 | 3.0 | | 2.9 | | |
| | | | $V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OH} = -4mA$ | 2.58 | | | 2.48 | | - |
| V _{OL} | LOW Level Output Voltage | 2.0 | $V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 50 \mu A$ | | 0.0 | 0.1 | | 0.1 | V |
| | | 3.0 | $V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 50 \mu A$ | | 0.0 | 0.1 | | 0.1 | |
| | | | $V_{IN} = V_{IL} \text{ or } V_{IH},$ $I_{OL} = 4mA$ | | | 0.36 | | 0.44 | |
| I _{IN} | Input Leakage Current | 3.6 | $V_{IN} = 5.5V \text{ or GND}$ | | | ±0.1 | | ±1.0 | μA |
| I _{CC} | Quiescent Supply Current | 3.6 | $V_{IN} = V_{CC}$ or GND | | | 2.0 | | 20.0 | μA |

Noise Characteristics⁽²⁾

| | | | | $T_A = 25^{\circ}C$ | | |
|------------------|--|---------------------|---------------------|---------------------|-------|-------|
| Symbol | Parameter | V _{CC} (V) | C _L (pF) | Тур. | Limit | Units |
| V _{OLP} | Quiet Output Maximum Dynamic V _{OL} | 3.3 | 50 | 0.3 | 0.5 | V |
| V _{OLV} | Quiet Output Minimum Dynamic V _{OL} | 3.3 | 50 | -0.3 | -0.5 | V |
| V _{IHD} | Minimum HIGH Level Dynamic Input Voltage | 3.3 | 50 | | 2.0 | V |
| V _{ILD} | Maximum LOW Level Dynamic Input Voltage | 3.3 | 50 | | 0.8 | V |

Note:

2. Input $t_r = t_f = 3ns$

AC Electrical Characteristics

| | | | | T _A = +25°C | | T _A = -40°C to +85°C | | | |
|---------------------------------------|--------------------------------------|---------------------|---------------------|------------------------|------|------------------------------------|------|------|-------|
| Symbol | Parameter | V _{CC} (V) | C _L (pF) | Min. | Тур. | Max. | Min. | Max. | Units |
| t _{PLH} , t _{PHL} | Propagation Delay Time | 2.7 | 15 | | 7.5 | 14.5 | 1.0 | 17.5 | ns |
| | | | 50 | | 10.0 | 18.0 | 1.0 | 21.0 | |
| | | 3.3 ± 0.3 | 15 | | 5.8 | 9.3 | 1.0 | 11.0 | |
| | | | 50 | | 8.3 | 12.8 | 1.0 | 14.5 | |
| t _{OSLH} , t _{OSHL} | Output to Output Skew ⁽³⁾ | 2.7 | 50 | | | 1.5 | | 1.5 | ns |
| | | 3.3 |] | | | 1.5 | | 1.5 | |

Note:

3. Parameter guaranteed by design $t_{OSLH} = |t_{PLHm} - t_{PLHn}|$, $t_{OSHL} = |t_{PHLm} - t_{PHLn}|$

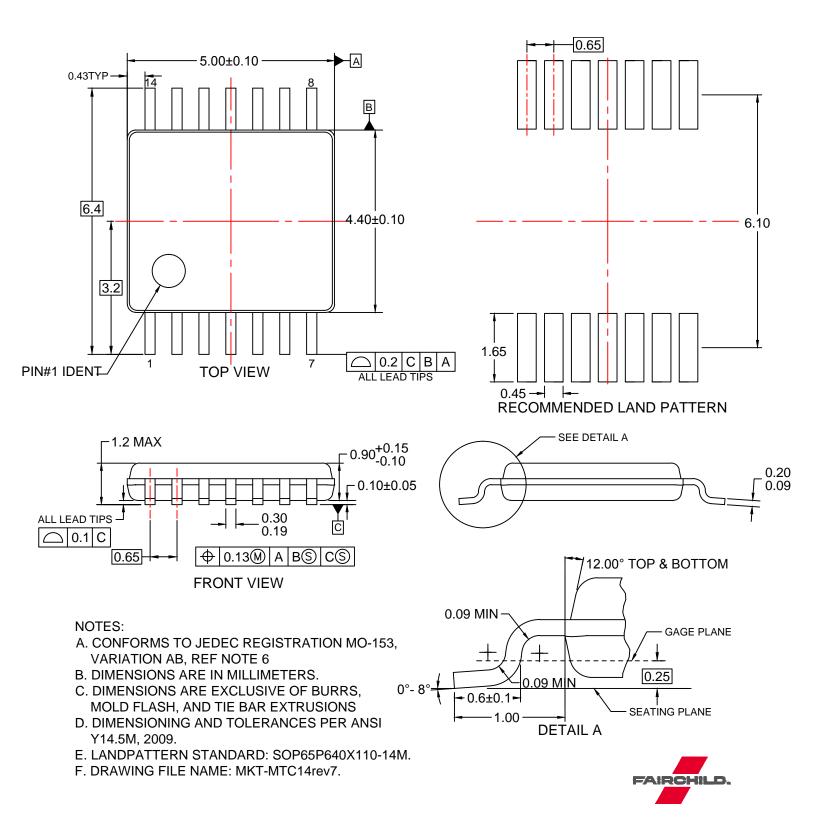
Capacitance

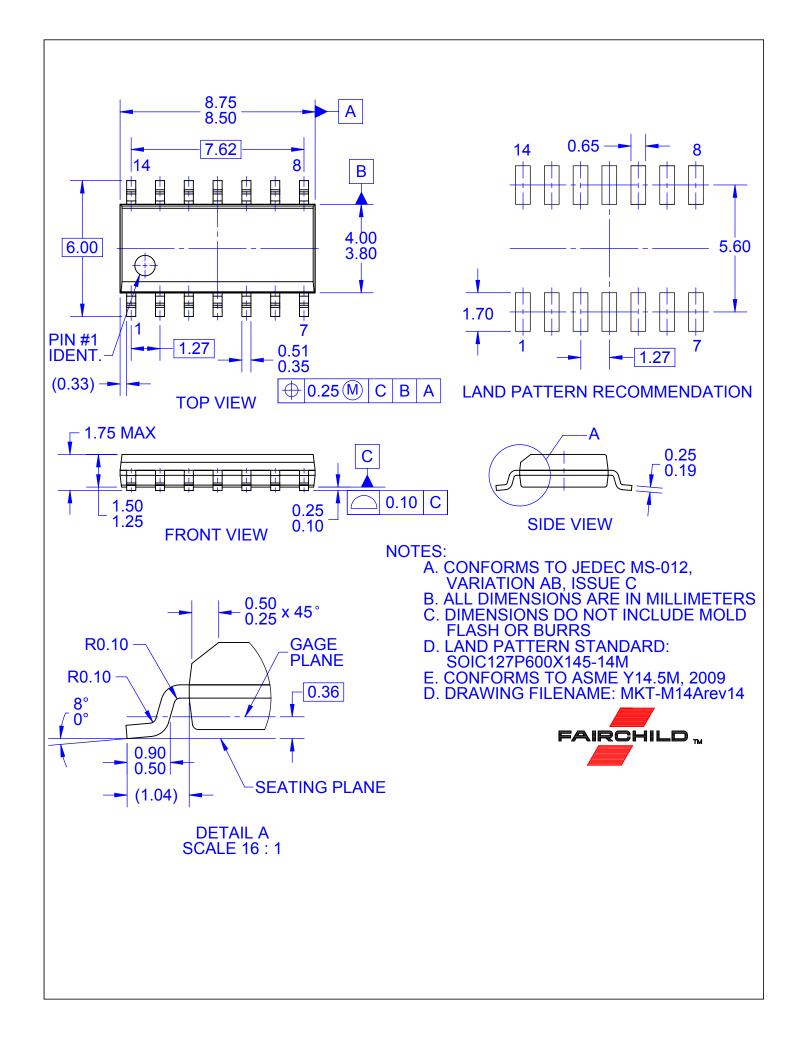
| | | T _A = +25°C | | T _A = -40°C to +85°C | | | |
|-----------------|--|------------------------|------|------------------------------------|------|------|-------|
| Symbol | Parameter | Min. | Тур. | Max. | Min. | Max. | Units |
| C _{IN} | Input Capacitance | | 4 | 10 | | 10 | pF |
| C _{PD} | Power Dissipation Capacitance ⁽⁴⁾ | | 18 | | | | pF |

Note:

4. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation: $I_{CC(opr.)} = \frac{C_{PD} \times V_{CC} \times f_{IN} \times I_{CC}}{4 \text{ (per Gate)}}$





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